TOSHIBA

TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process)

2SA966

Audio Power Amplifier Applications

• Complementary to 2SC2236 and 3-W output applications.

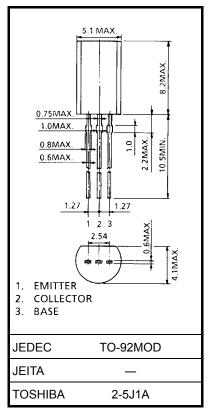
Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V _{CBO}	-30	V
Collector-emitter voltage	V _{CEO}	-30	V
Emitter-base voltage	V _{EBO}	-5	V
Collector current	Ι _C	-1.5	А
Emitter current	ΙE	1.5	А
Collector power dissipation	PC	900	mW
Junction temperature	Тј	150	°C
Storage temperature range	T _{stg}	-55 to 150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling

Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).



Weight: 0.36 g (typ.)

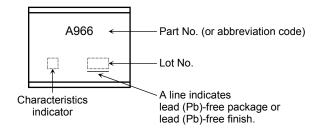
Unit: mm

Electrical Characteristics (Ta = 25°C)

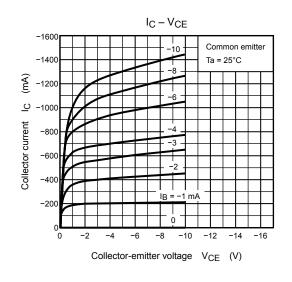
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	$V_{CB} = -30 V, I_{E} = 0$	—	_	-100	nA
Emitter cut-off current	I _{EBO}	V _{EB} = -5 V, I _C = 0	_	_	-100	nA
Collector-emitter breakdown voltage	V (BR) CEO	I _C = -10 mA, I _B = 0	-30	_	—	V
Emitter-base breakdown voltage	V (BR) EBO	$I_{E} = -1 \text{ mA}, I_{C} = 0$	-5	_	—	V
DC current gain	h _{FE} (Note)	V _{CE} = -2 V, I _C = -500 mA	100		320	
Collector-emitter saturation voltage	V _{CE (sat)}	I _C = -1.5 A, I _B = -0.03 A	_		-2.0	V
Base-emitter voltage	V _{BE}	V _{CE} = −2 V, I _C = −500 mA	_	_	-1.0	V
Transition frequency	f _T	V _{CE} = −2 V, I _C = −500 mA	_	120	—	MHz
Collector output capacitance	C _{ob}	V _{CB} = −10 V, I _E = 0, f = 1 MHz	_	40	_	pF

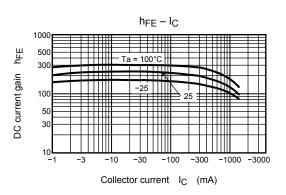
Note: h_{FE} classification O: 100 to 200, Y: 160 to 320

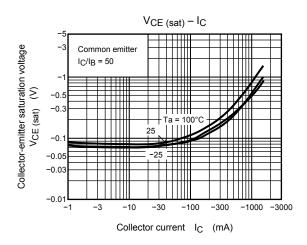
Marking

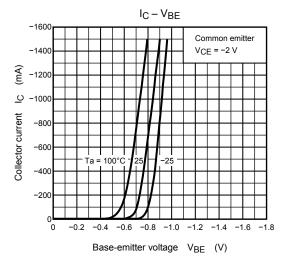


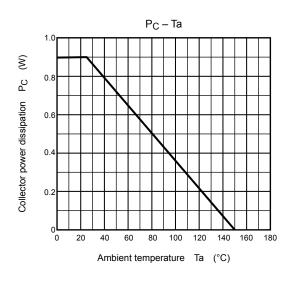
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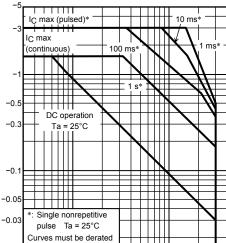












Collector-emitter voltage V_{CE} (V)

-3

VCEO max

-30

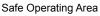
-10

linearly with increase in

-1

temperature.

-0.01 -0.3



E

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Collector current

RESTRICTIONS ON PRODUCT USE

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